

Ultra-high light yield solutions (from IHEP)



- Low temperature CsI+SiPM+TPB solution
- CsI, LY > 100000 photons/MeV, 2.5 times better than CsI(Na)
- SiPM, PDE 50%-60%, 2 times better than PMT
- Expected ~50-60 p.e./keVee



CsI



SiPM



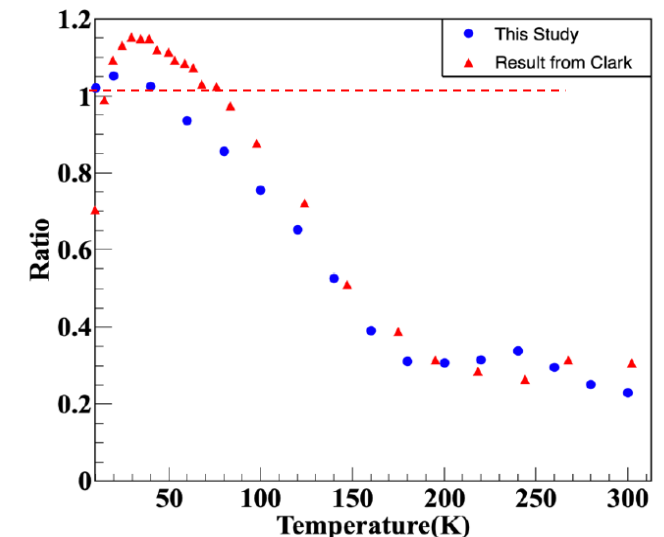
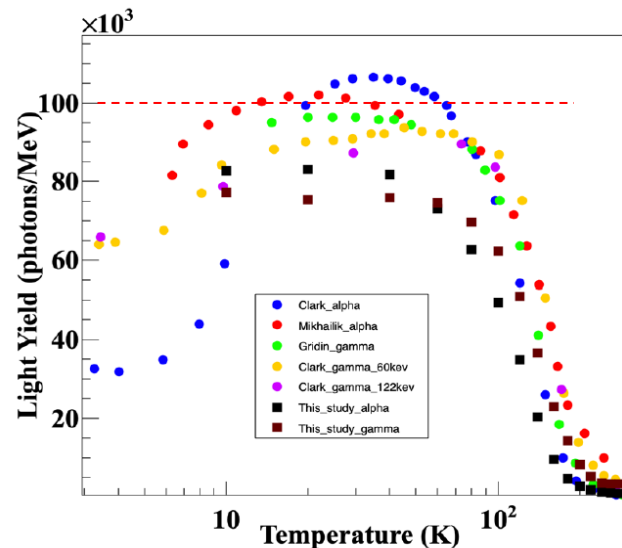
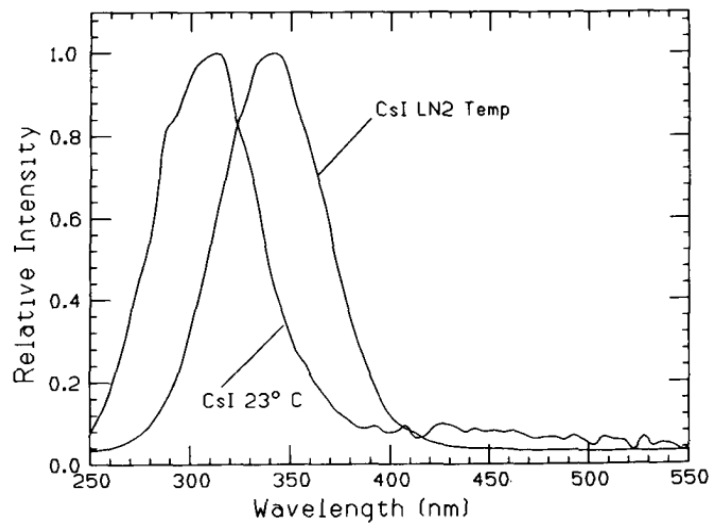
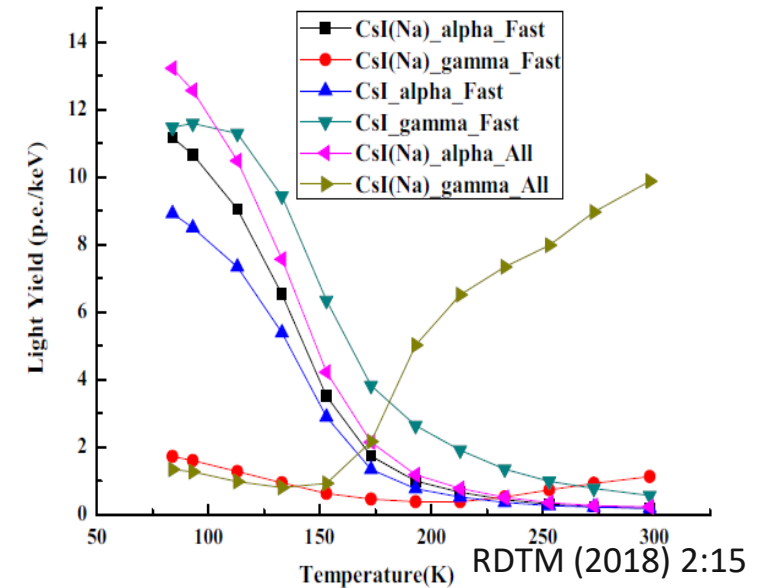
TPB (WLS)

Low temperature

Pure CsI crystals



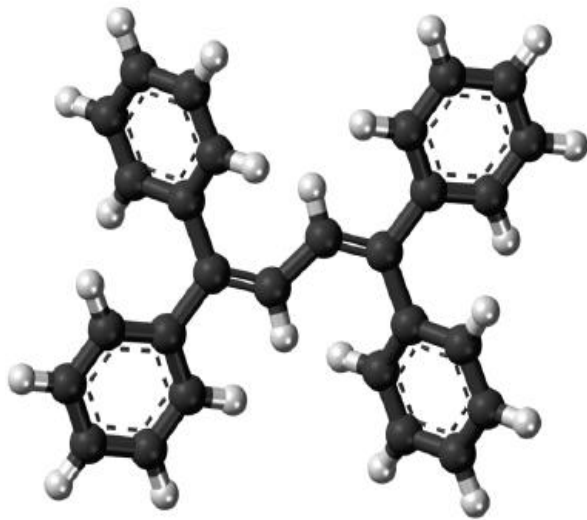
- LY be significantly improved at LT
- The brightest scintillator, 310-340 nm
- QF > 100% for alpha/gamma
- QF for nuclear recoil/gamma 10%, 20%???
- LY of CsI(Na), CsI(Tl) is reduced at LT



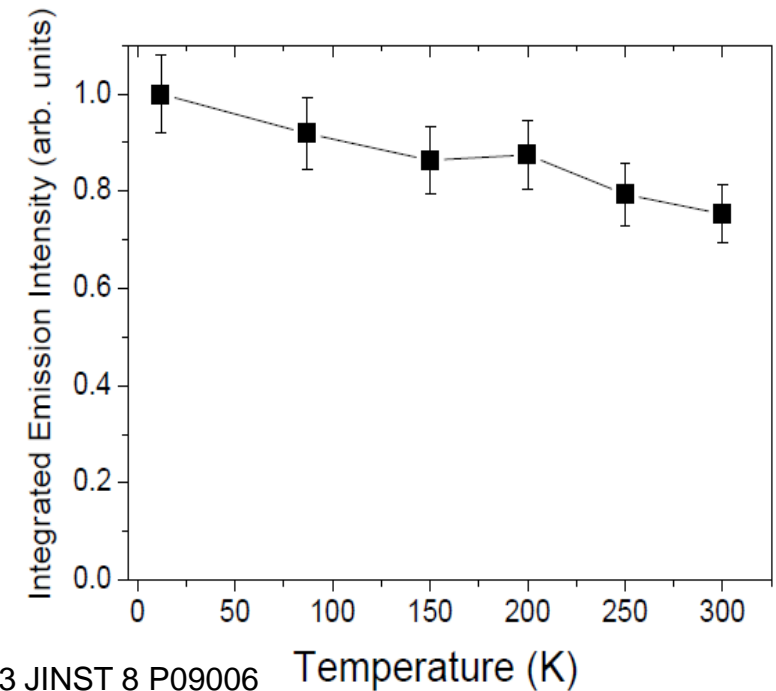
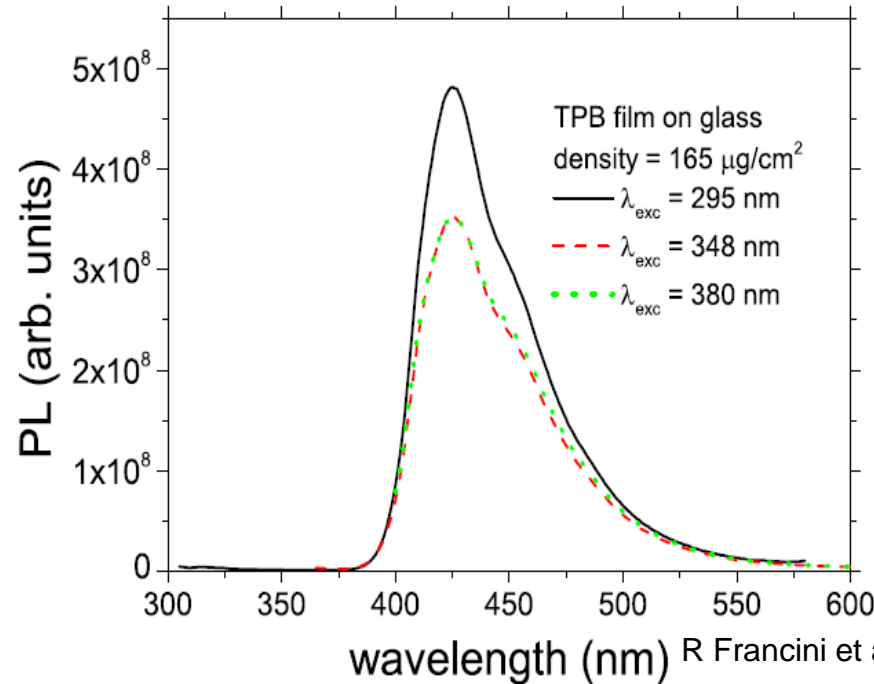
TPB wavelength shifter



- Shift 340nm to 420 nm, match the SiPMs sensitive spectrum
- Performance is enhanced at LT
- Widely used in liquid argon detectors



Tetraphenyl Butadiene (TPB)

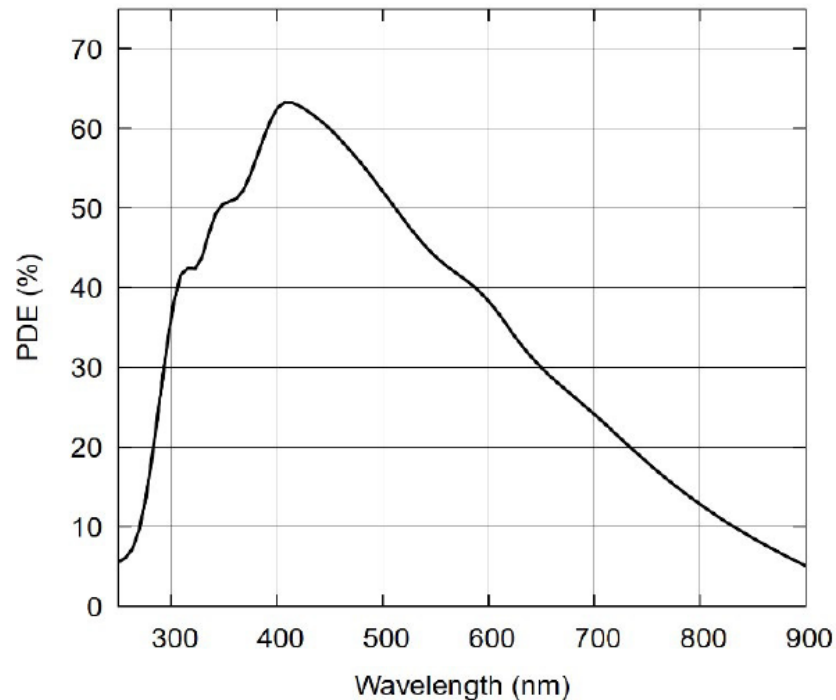


R Francini et al 2013 JINST 8 P09006

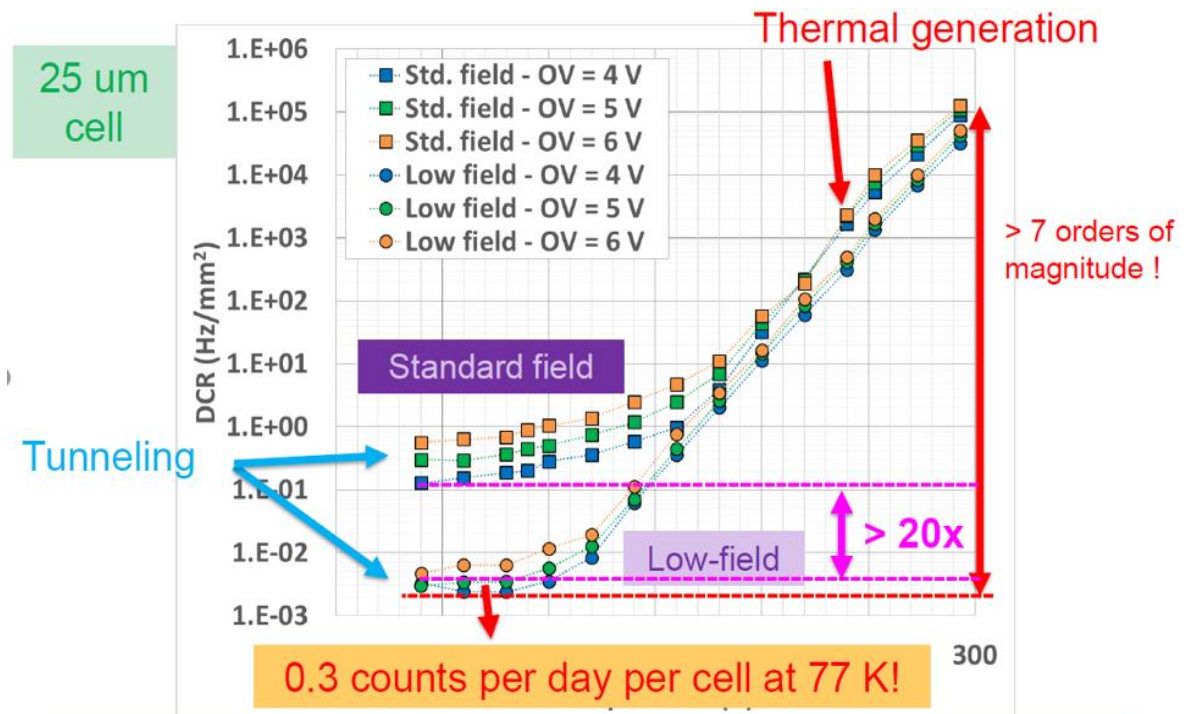
SiPMs Performance



- PDE 50-60% at 420 nm
- DCR reduced by 7 orders, < 0.01 CPS/mm² at 77K
- Optical cross talk, acts as a photon amplifier



AFBR-S4N66P014M NUV-MT Silicon Photomultiplier

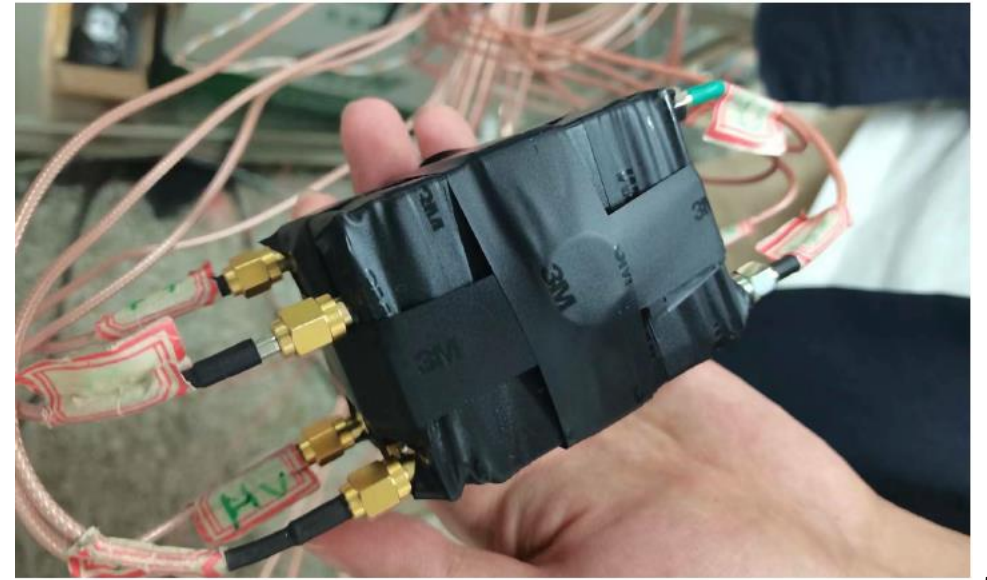
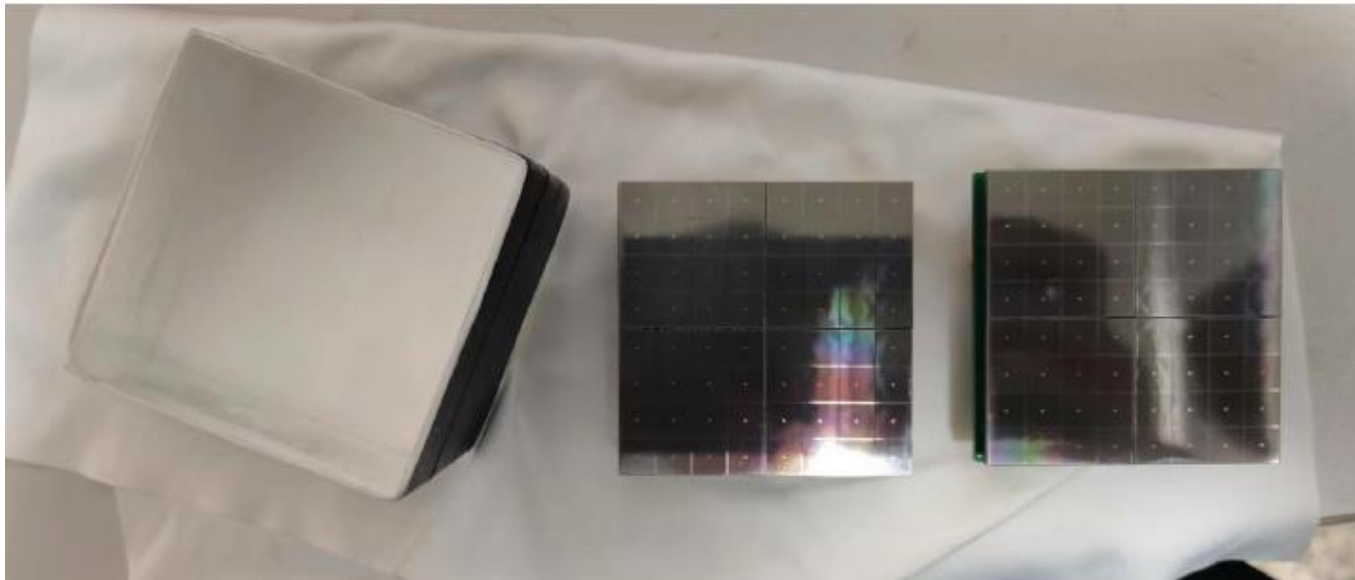


A 10x10 cm² SiPM array would have a total DCR < 100 cps!

Prototype detector



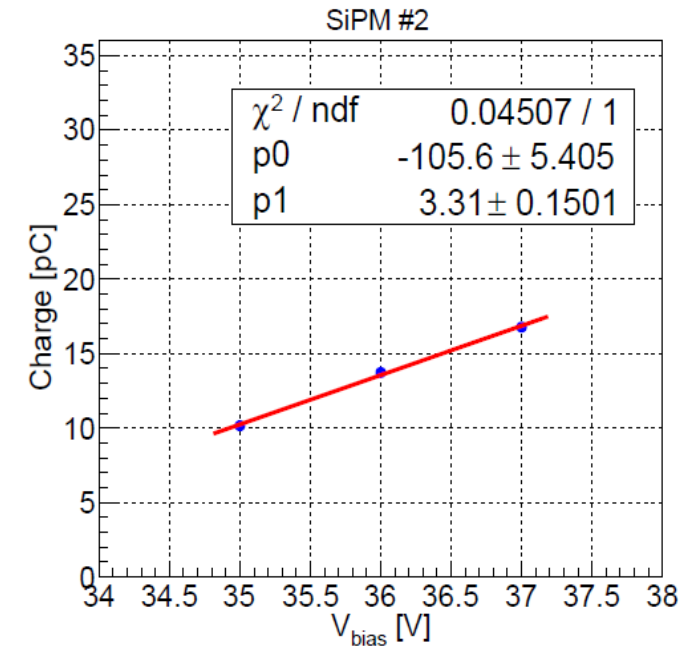
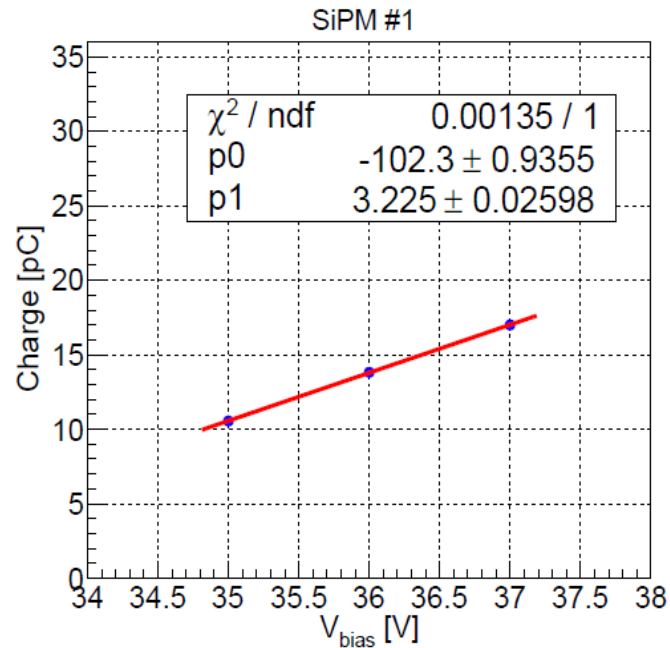
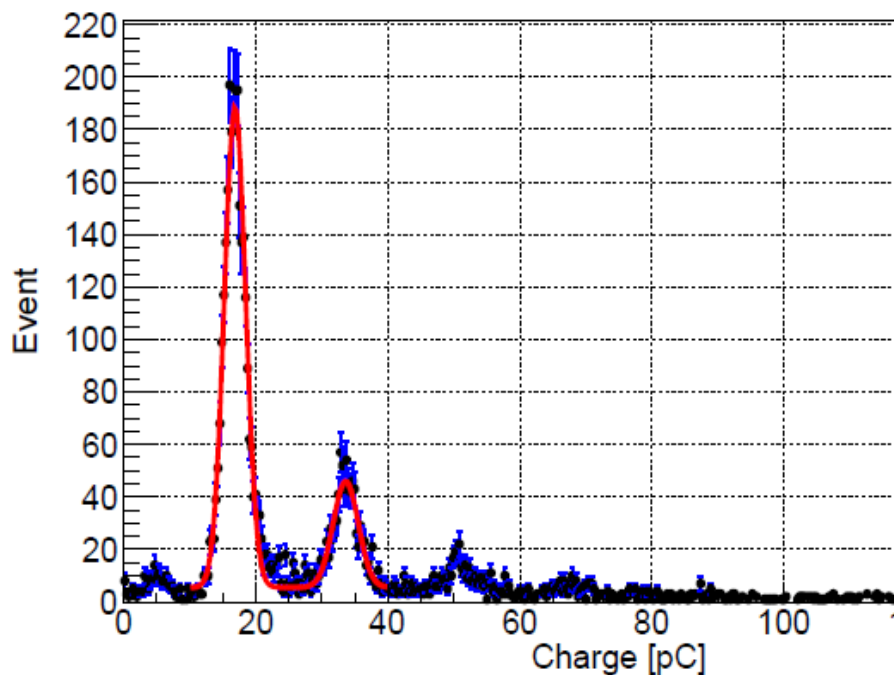
- CsI crystal 5x5x5 cm, 0.56kg, polished
- Packaging with Teflon reflective film without TPB
- SiPMs array, 5x5 cm, two end readout, with TPB
- Cooling to 77 K with liquid nitrogen
- Low temperature front-end amplifier circuit



SiPMs array performance



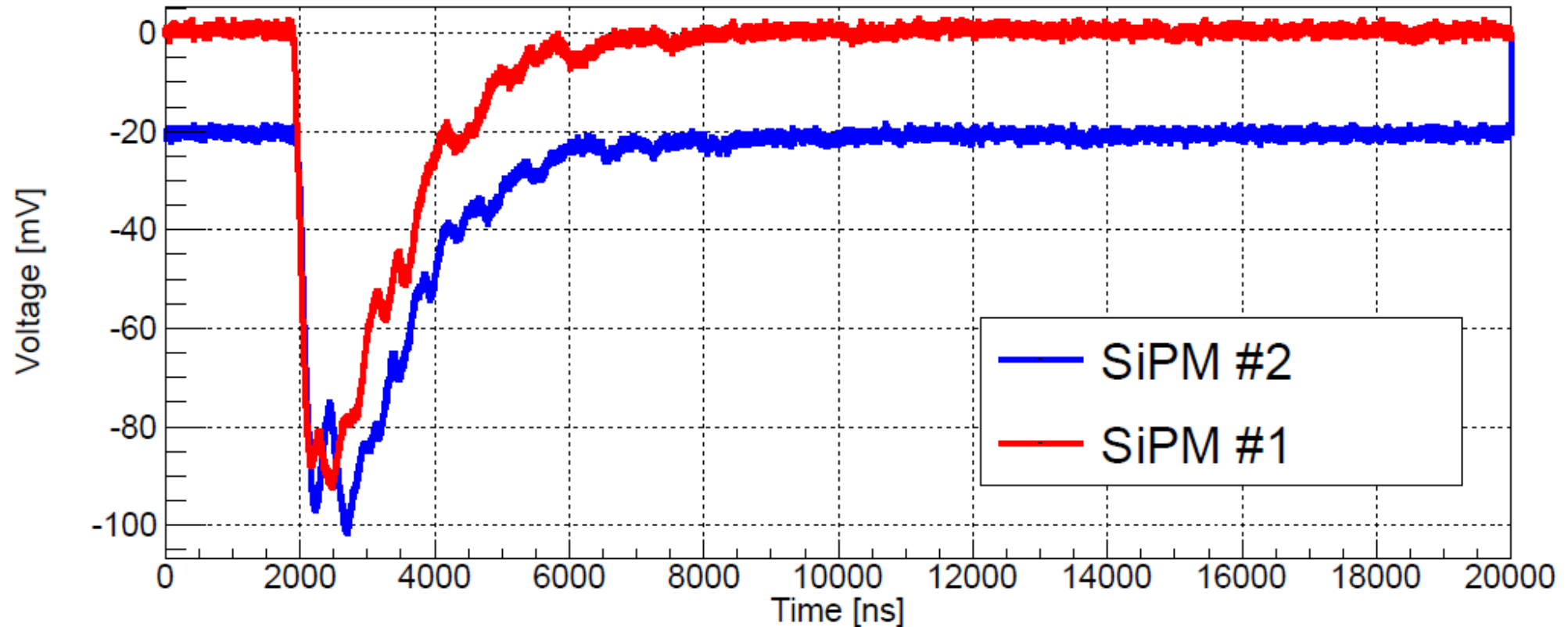
- SiPM and preamplifier run stably at low temperatures
- Single photoelectron resolution is very good
- Consistency of the two arrays is very good
- DCR ~ 0.1 Hz/mm² @35V bias



Waveform performance



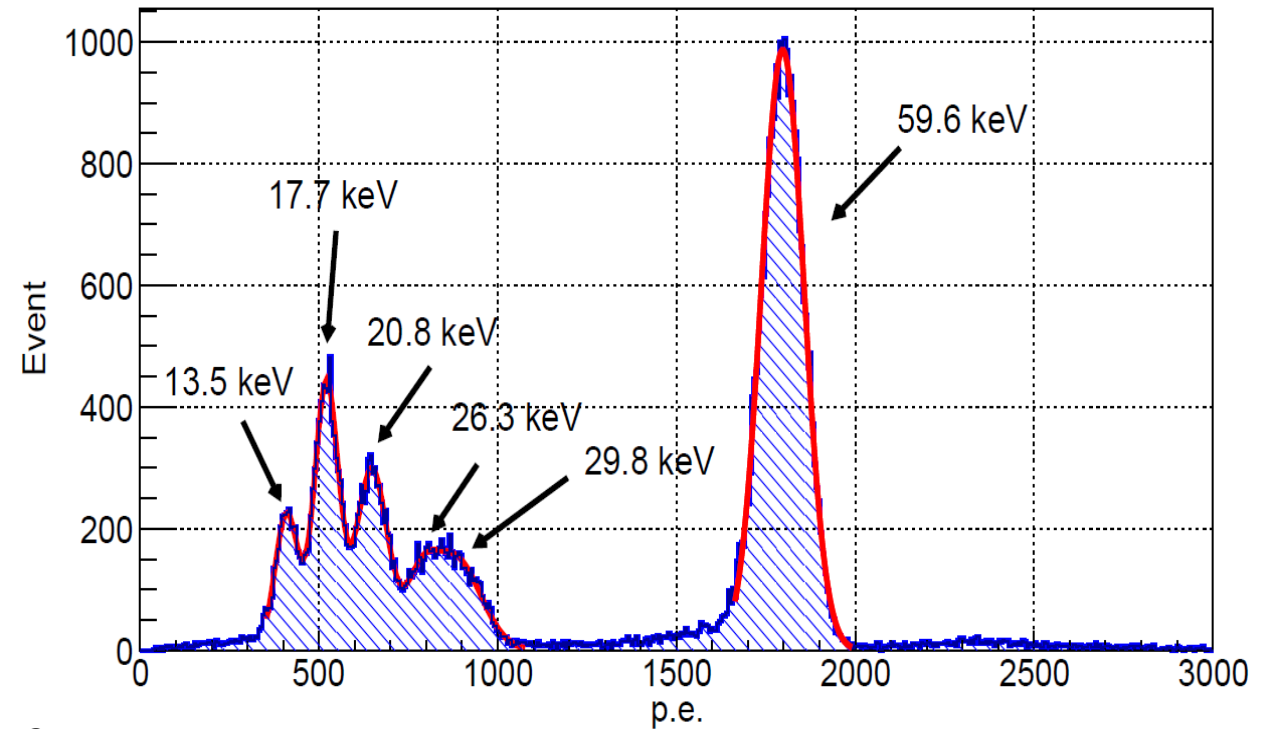
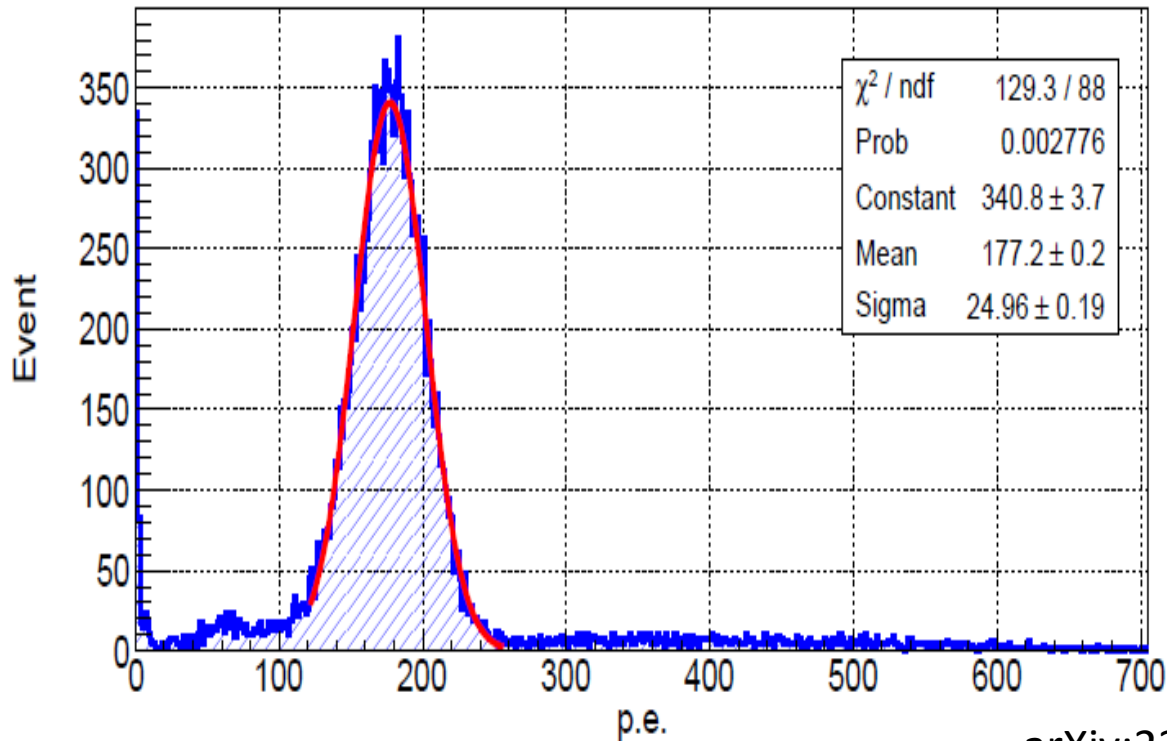
- Decay time $\sim 1 \mu\text{s}$, Pulse Width $\sim 3 \mu\text{s}$
- Baseline width $< 5 \text{ mV}$



Energy spectrum



- Test with ^{241}Am and ^{55}Fe
- Excellent energy resolution, fine structures are clearly visible

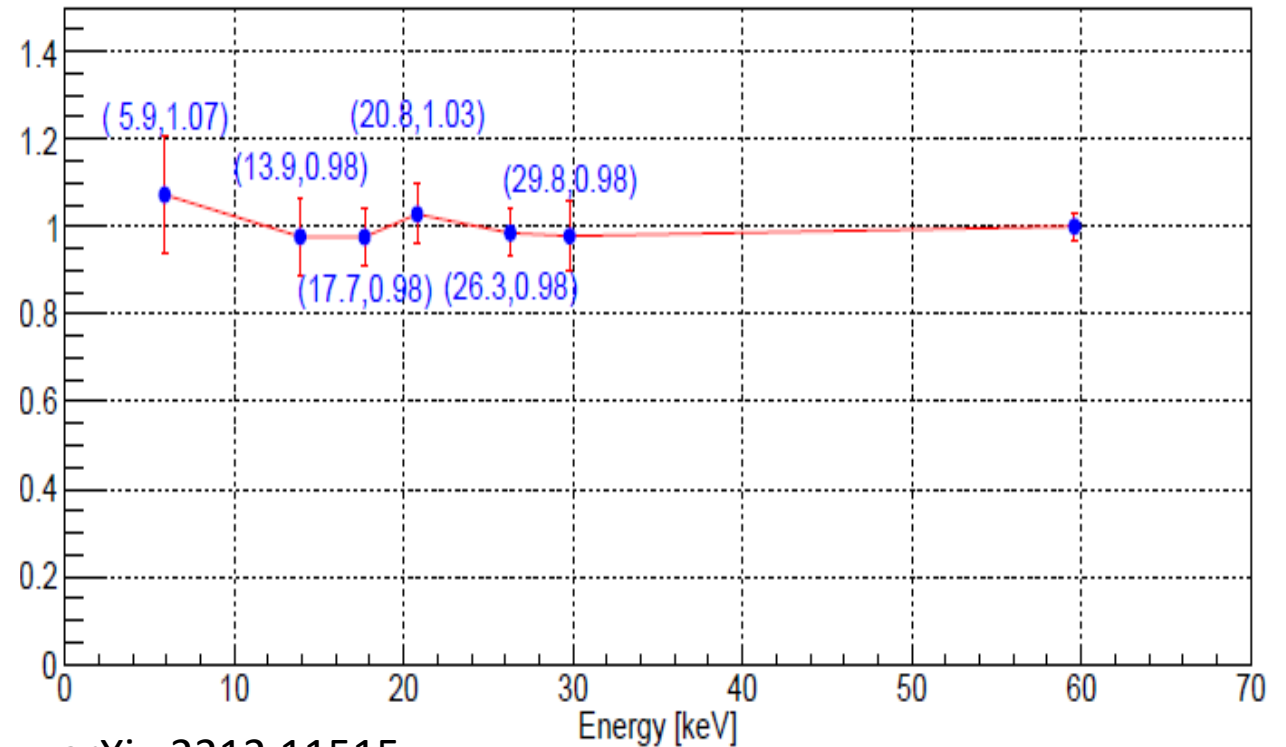
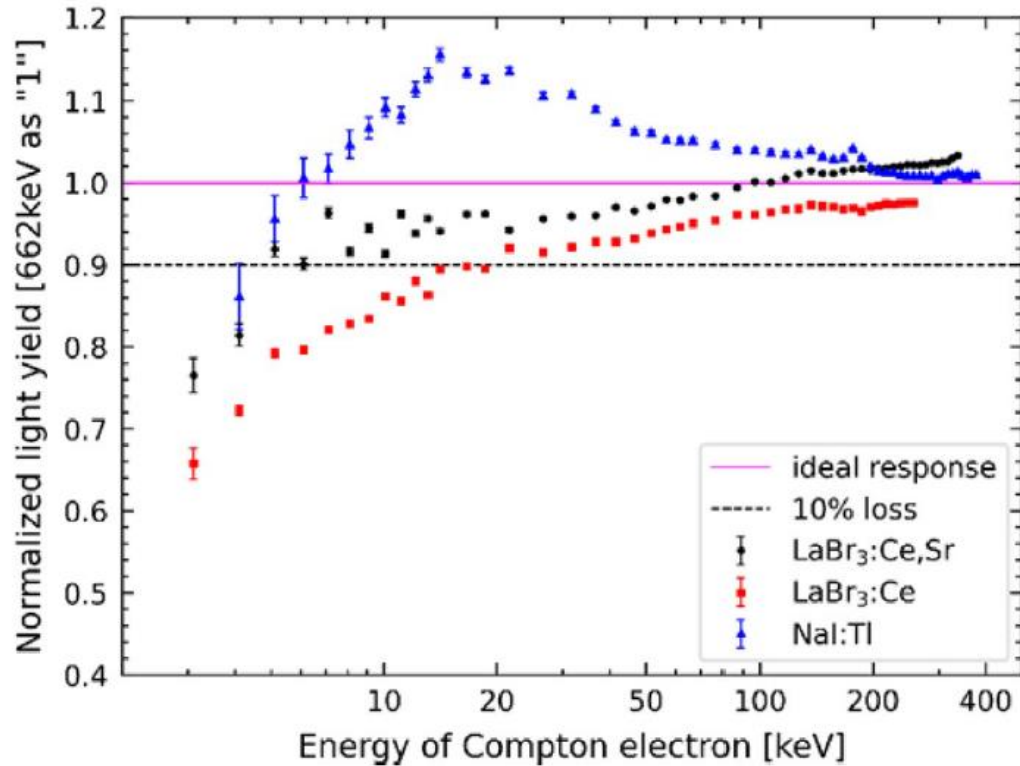


arXiv:2212.11515

Luminescence linearity



- Excellent luminescence linearity, no drop down below 10keV
- Significantly better than LaBr_3 , NaI:Tl

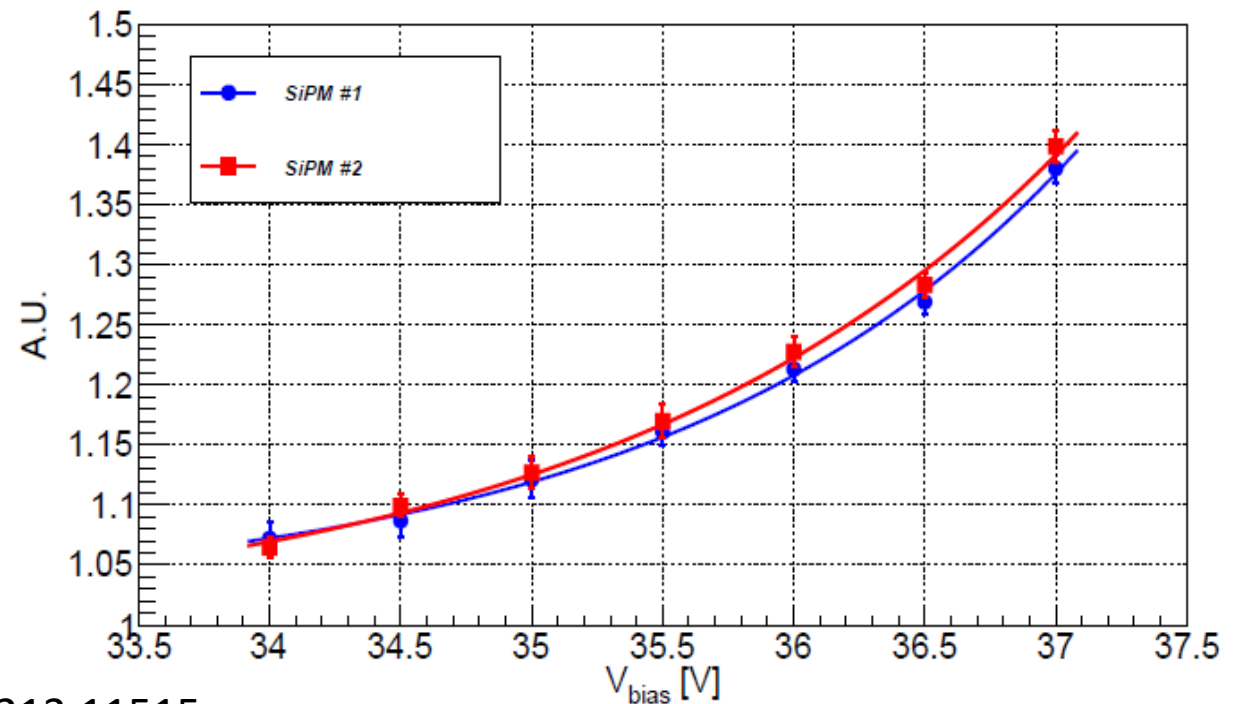
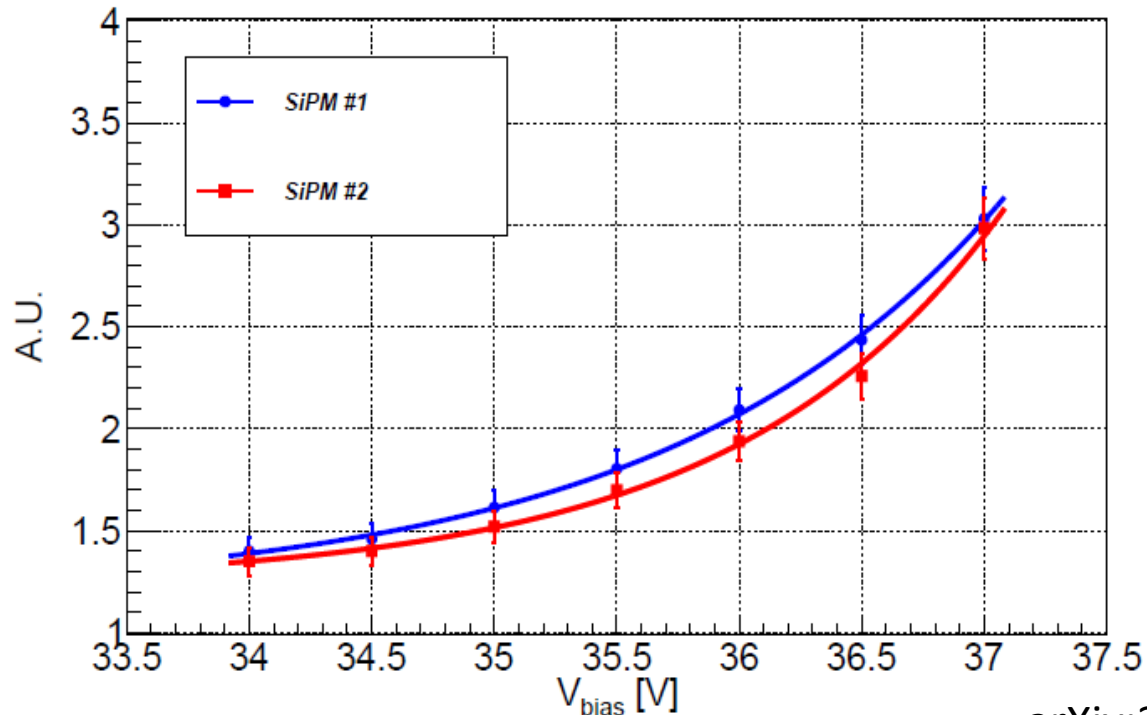


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Influence of SiPMs Cross Talk and After Pulse



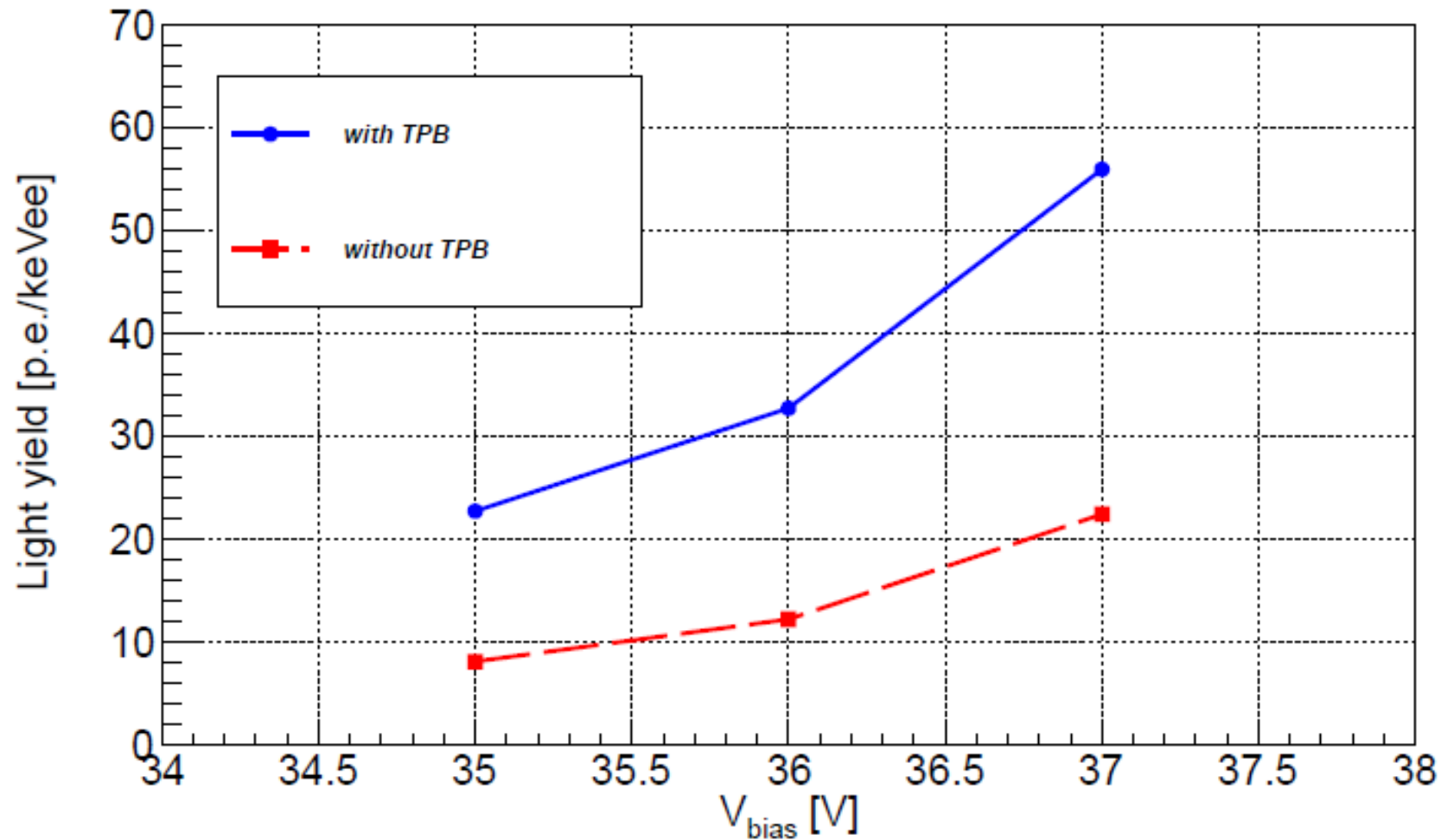
- CT, AP significantly increasing the measured p.e. number
- Internal CT, AP triples the number of p.e. at $37 V_{\text{bias}}$
- External CT 1.4 times the number of p.e. at $37 V_{\text{bias}}$



arXiv:2212.11515



- Photoelectrons number is doubled with TPB

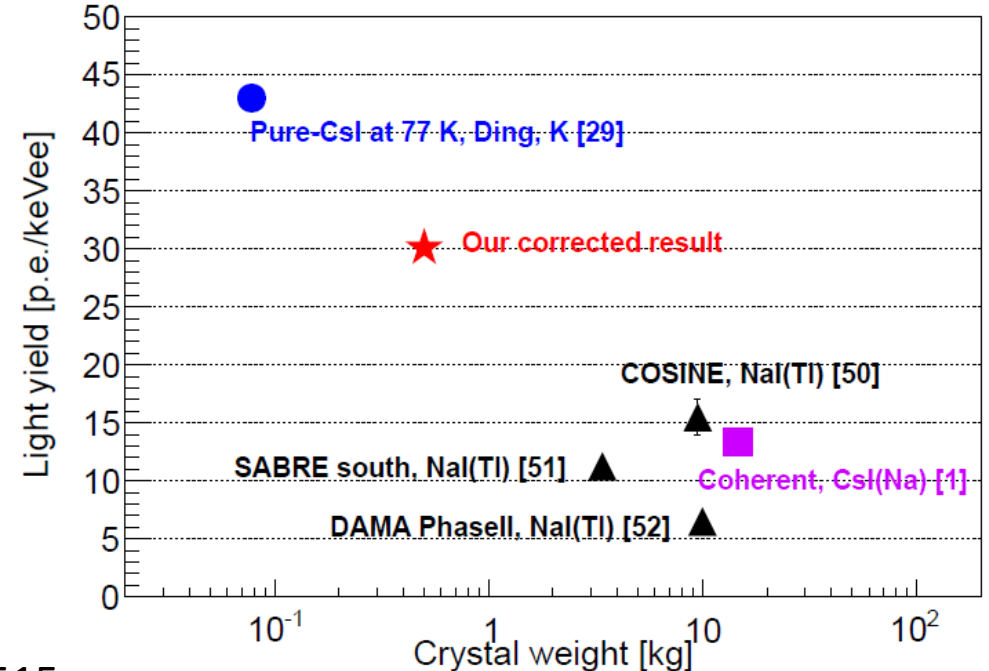


Light yield



- The measured p.e. number increases significantly with increasing bias voltage, 30 to 122 p.e. /keVee
- 122.7 p.e./keVee, a world record
- 30.1 p.e./keVee, after CT subtract (50% PDE at LT?)

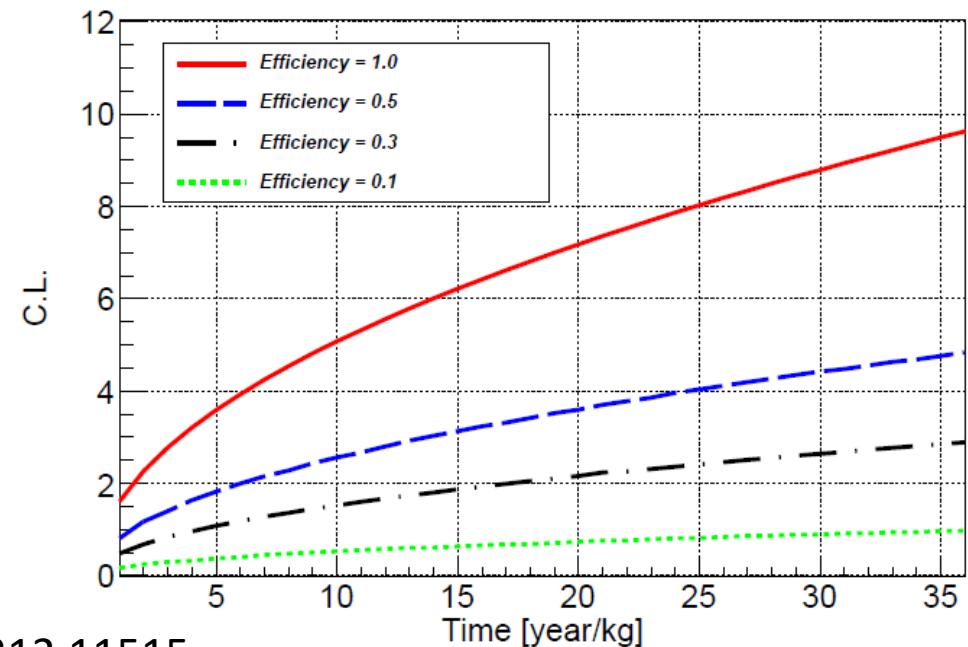
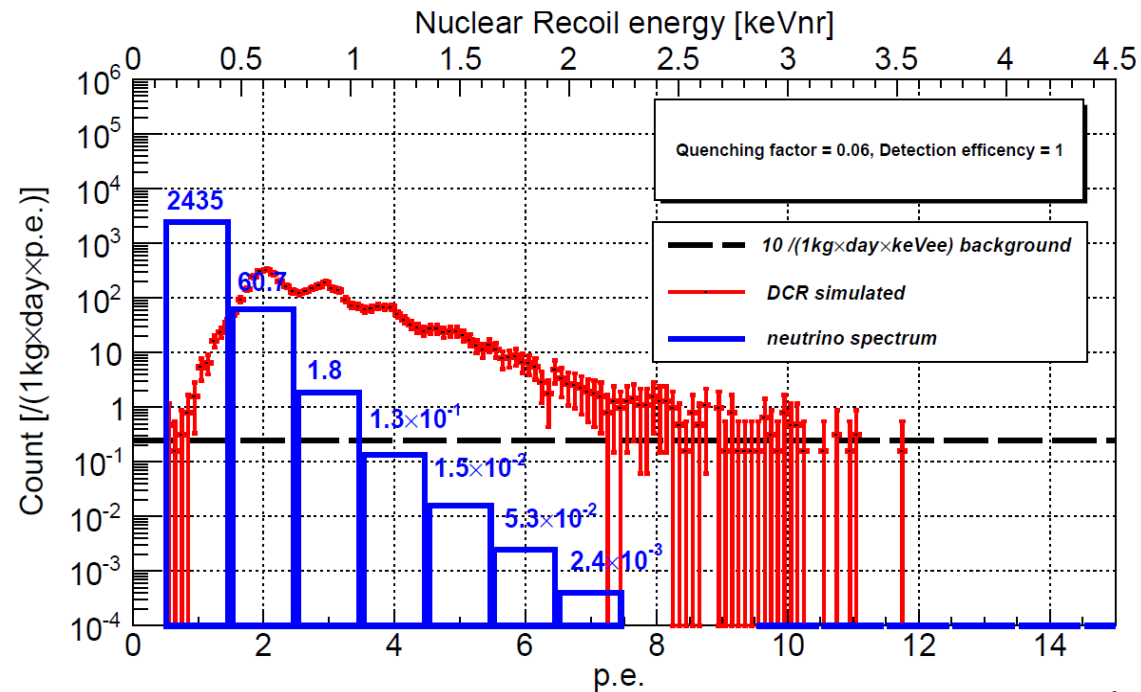
V_{bias} (V)	p.e.	resolution	measured LY	corrected LY
34.0	176.8	14.3%	30.0 ± 4.3	20.9 ± 3.1
34.5	206.4	14.4%	35.0 ± 5.0	23.4 ± 3.6
35.0	241.4	14.4%	40.9 ± 5.9	25.8 ± 4.0
35.5	286.7	15.4%	48.6 ± 7.5	26.7 ± 4.3
36.0	359.4	16.2%	60.9 ± 9.9	28.2 ± 4.8
36.5	473.5	19.7%	80.2 ± 15.8	29.0 ± 5.9
37.0	723.8	26.0%	122.7 ± 32.2	30.1 ± 8.1



Potentials in the CEvNS detection



- 35 m distance to a 4.6 GWth reactor
- QF=0.06, DCR= 0.1 CPS/mm², DCR dominant background,
- Threshold 2 p.e., good chance for reactor CEvNS observation
- If QF ~15%?, DCR~0.01?, better sensitivity

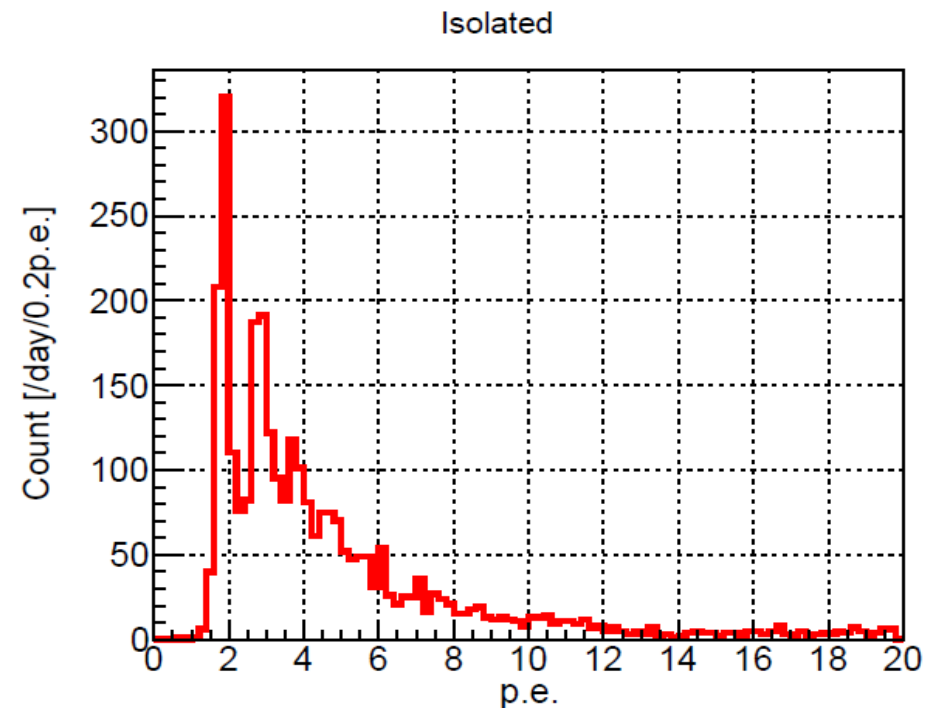
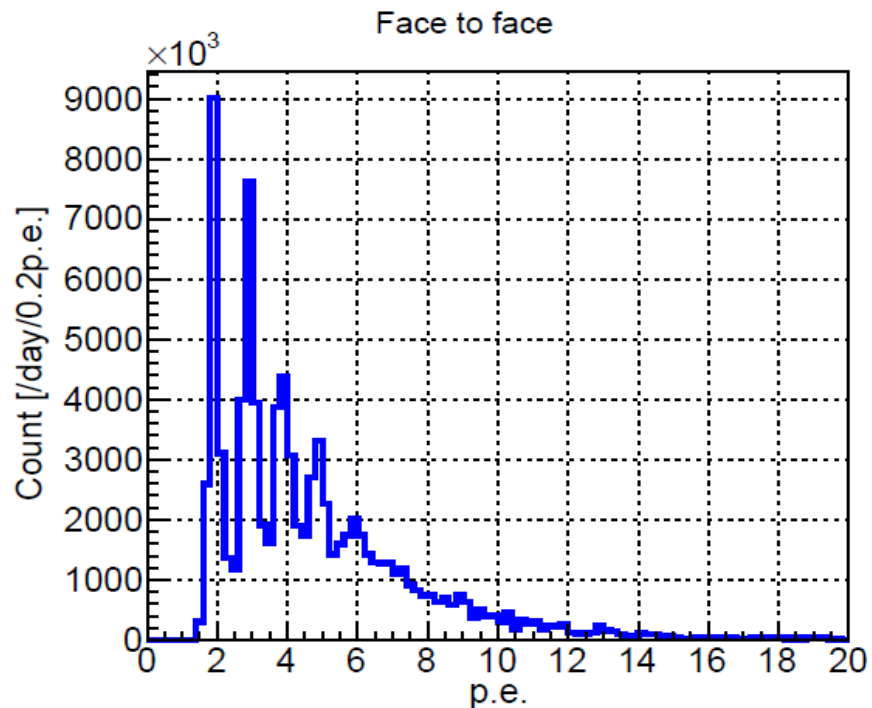


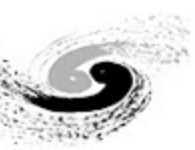
arXiv:2212.11515

Issue of SiPMs eCT coincidence events



- Events rate of eCT coincidence is very high
- 5 orders larger than accidental coincidence of DCR
- Big issue for low threshold detectors
- Need do further study, single-ended readout, correlation with iCT





- **Ultra-high light yield solution is proposed by IHEP**
- **The prototype detector works well**
- **Good chance for reactor CEvNS detection**
- **eCT issue need further study**